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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re PATENT APPLICATION of

Jun Kanamori

Group Art Unit: 2814

Serial No.: 09/398,189

Examiner: S. Rao

Filed: September 17, 1999

For: METHOD OF FABRICATING A SEMICONDUCTOR DEVICE WITH SELF-  
ALIGNED SILICIDE AREAS FORMED USING A SUPPLEMENTAL SILICON  
OVERLAYER

AMENDMENT UNDER 37 C.F.R. 1.116

Honorable Assistant Commissioner for Patents  
Washington, D.C. 20231

Date: December 10, 2002

Sir:

In response to the Final Office Action dated August 12, 2002, the period for response having been extended one month to December 12, 2002, the following amendments and remarks are respectfully submitted in connection with the above-identified application.

In the Claims:

The following replacement claims are respectfully submitted:

2. (Four Times Amended) The method according to claim 30, wherein the material to be silicided comprises cobalt.

3. (Four Times Amended) The method according to claim 30, wherein the